

Lonten N-channel 800V, 5A, 0.98Ω LonFET™ Power MOSFET

Description

LonFET™ Power MOSFET is fabricated using advanced super junction technology. The resulting device has extremely low on resistance, making it especially suitable for applications which require superior power density and outstanding efficiency.

Features

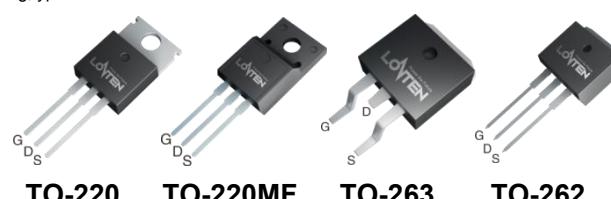
- ◆ Ultra low $R_{DS(on)}$
- ◆ Ultra low gate charge (typ. $Q_g = 14.5\text{nC}$)
- ◆ 100% UIS tested
- ◆ RoHS compliant

Applications

- ◆ Power factor correction (PFC).
- ◆ Switched mode power supplies (SMPS).
- ◆ Uninterruptible power supply (UPS).

Product Summary

| | |
|----------------------|--------|
| $V_{DS} @ T_{j,max}$ | 850V |
| $R_{DS(on),max}$ | 0.98Ω |
| I_{DM} | 5A |
| $Q_{g,typ}$ | 14.5nC |



TO-220 TO-220MF TO-263 TO-262
TO-252 TO-251



N-Channel MOSFET



Absolute Maximum Ratings

| Parameter | Symbol | Value | Unit |
|---|----------------|-------------|---------------------|
| Drain-Source Voltage | V_{DSS} | 800 | V |
| Continuous drain current ($T_c = 25^\circ\text{C}$) | I_D | 5 | A |
| ($T_c = 100^\circ\text{C}$) | | 3 | A |
| Pulsed drain current ¹⁾ | I_{DM} | 15 | A |
| Gate-Source voltage | V_{GSS} | ± 30 | V |
| Avalanche energy, single pulse ²⁾ | E_{AS} | 120 | mJ |
| Avalanche current, repetitive ³⁾ | I_{AR} | 5 | A |
| Power Dissipation TO-220MF ($T_c = 25^\circ\text{C}$) | P_D | 29 | W |
| - Derate above 25°C | | 0.23 | W/ $^\circ\text{C}$ |
| Power Dissipation TO-220/TO-252/TO-263 ($T_c = 25^\circ\text{C}$) | P_D | 50 | W |
| - Derate above 25°C | | 0.4 | W/ $^\circ\text{C}$ |
| Operating and Storage Temperature Range | T_J, T_{STG} | -55 to +150 | $^\circ\text{C}$ |
| Continuous diode forward current | I_S | 5 | A |
| Diode pulse current | $I_{S,pulse}$ | 15 | A |

Thermal Characteristics TO-220/TO-252/TO-263

| Parameter | Symbol | Value | Unit |
|---|-------------------|-------|------|
| Thermal Resistance, Junction-to-Case | $R_{\theta JC}$ | 2.5 | °C/W |
| Thermal Resistance, Junction-to-Ambient | $R_{\theta JA}$ | 62 | °C/W |
| Soldering temperature, wavesoldering only allowed at leads. (1.6mm from case for 10s) | T_{sold} | 260 | °C |

Thermal Characteristics TO-220MF

| Parameter | Symbol | Value | Unit |
|---|-------------------|-------|------|
| Thermal Resistance, Junction-to-Case | $R_{\theta JC}$ | 4.3 | °C/W |
| Thermal Resistance, Junction-to-Ambient | $R_{\theta JA}$ | 80 | °C/W |
| Soldering temperature, wavesoldering only allowed at leads. (1.6mm from case for 10s) | T_{sold} | 260 | °C |

Package Marking and Ordering Information

| Device | Device Package | Marking | Units/Tube | Units/Reel |
|-------------|----------------|-------------|------------|------------|
| LSC80R980GT | TO-220 | LSC80R980GT | 50 | |
| LSD80R980GT | TO-220MF | LSD80R980GT | 50 | |
| LSE80R980GT | TO-263 | LSE80R980GT | | 800 |
| LSF80R980GT | TO-262 | LSF80R980GT | 50 | |
| LSG80R980GT | TO-252 | LSG80R980GT | | 2500 |
| LSH80R980GT | TO-251 | LSH80R980GT | 72 | |

Electrical Characteristics

$T_c = 25^\circ\text{C}$ unless otherwise noted

| Parameter | Symbol | Test Condition | Min. | Typ. | Max. | Unit |
|----------------------------------|---------------------|--|------|------|------|---------------|
| Static characteristics | | | | | | |
| Drain-source breakdown voltage | BV_{DSS} | $V_{GS}=0 \text{ V}, I_D=0.25 \text{ mA}$ | 800 | - | - | V |
| Gate threshold voltage | $V_{GS(\text{th})}$ | $V_{DS}=V_{GS}, I_D=0.25 \text{ mA}$ | 2.5 | 3.5 | 4.5 | V |
| Drain cut-off current | I_{DSS} | $V_{DS}=800 \text{ V}, V_{GS}=0 \text{ V},$ $T_j = 25^\circ\text{C}$ $T_j = 125^\circ\text{C}$ | - | - | 1 | μA |
| Gate leakage current, Forward | I_{GSSF} | $V_{GS}=30 \text{ V}, V_{DS}=0 \text{ V}$ | - | - | 100 | nA |
| Gate leakage current, Reverse | I_{GSSR} | $V_{GS}=-30 \text{ V}, V_{DS}=0 \text{ V}$ | - | - | -100 | nA |
| Drain-source on-state resistance | $R_{DS(on)}$ | $V_{GS}=10 \text{ V}, I_D=2.5 \text{ A}$ $T_j = 25^\circ\text{C}$ $T_j = 150^\circ\text{C}$ | - | 0.85 | 0.98 | Ω |
| Gate resistance | R_G | f=1 MHz, open drain | - | 7.5 | - | Ω |
| Dynamic characteristics | | | | | | |
| Input capacitance | C_{iss} | $V_{DS} = 100 \text{ V}, V_{GS} = 0 \text{ V},$ $f = 250 \text{ kHz}$ | - | 614 | - | pF |
| Output capacitance | C_{oss} | | - | 20 | - | |
| Reverse transfer capacitance | C_{rss} | | - | 2 | - | |

| | | | | | | |
|--------------------------------------|---------------|---|---|------|-----|---------|
| Turn-on delay time | $t_{d(on)}$ | $V_{DD} = 400V, I_D = 2.5A$ $R_G = 10\Omega, V_{GS}=10V$ | - | 13.5 | - | ns |
| Rise time | t_r | | - | 30 | - | |
| Turn-off delay time | $t_{d(off)}$ | | - | 56 | - | |
| Fall time | t_f | | - | 27 | - | |
| Gate charge characteristics | | | | | | |
| Gate to source charge | Q_{gs} | $V_{DD}=640 V, I_D=2.5A,$ $V_{GS}=0 \text{ to } 10 V$ | - | 3.5 | - | nC |
| Gate to drain charge | Q_{gd} | | - | 5.5 | - | |
| Gate charge total | Q_g | | - | 14.5 | - | |
| Gate plateau voltage | $V_{plateau}$ | | - | 5 | - | V |
| Reverse diode characteristics | | | | | | |
| Diode forward voltage | V_{SD} | $V_{GS}=0 V, I_F=2.5A$ | - | - | 1.4 | V |
| Reverse recovery time | t_{rr} | $V_R=50 V, I_F=2.5A,$ $dI_F/dt=100 A/\mu s$ | - | 250 | - | ns |
| Reverse recovery charge | Q_{rr} | | - | 1.69 | - | μC |
| Peak reverse recovery current | I_{rm} | | - | 13.5 | - | A |

Notes:

1. Limited by maximum junction temperature, maximum duty cycle is 0.75.
2. $I_{AS} = 2A$, $V_{DD} = 60V$, Starting $T_j = 25^\circ C$.
3. Repetitive Rating: Pulse width limited by maximum junction temperature.

Electrical Characteristics Diagrams

Figure 1. On-Region Characteristics

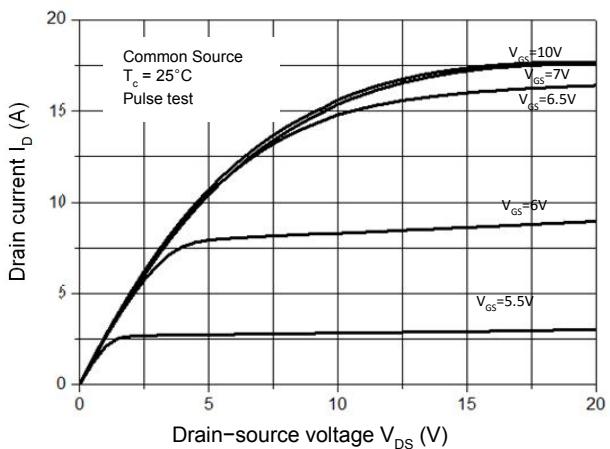


Figure 2. Transfer Characteristics

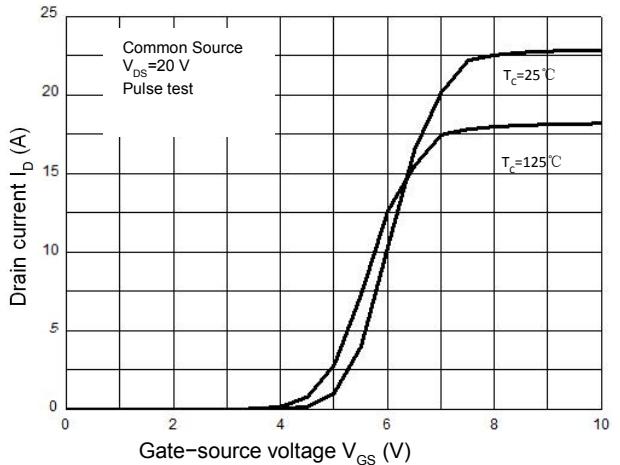


Figure 3. On-Resistance Variation vs. Drain Current

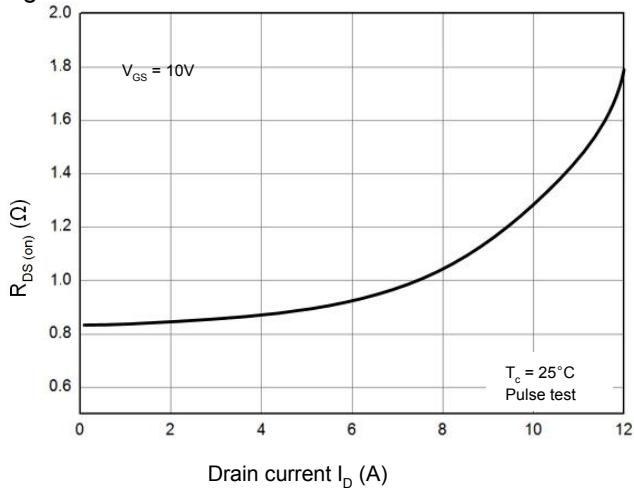


Figure 4. Threshold Voltage vs. Temperature

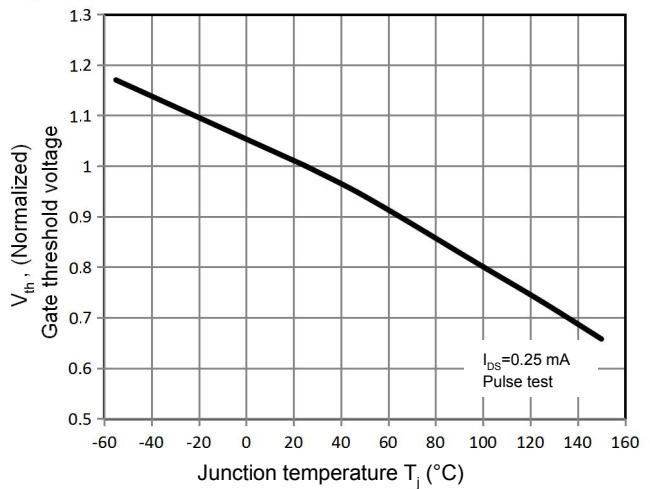


Figure 5. Breakdown Voltage vs. Temperature

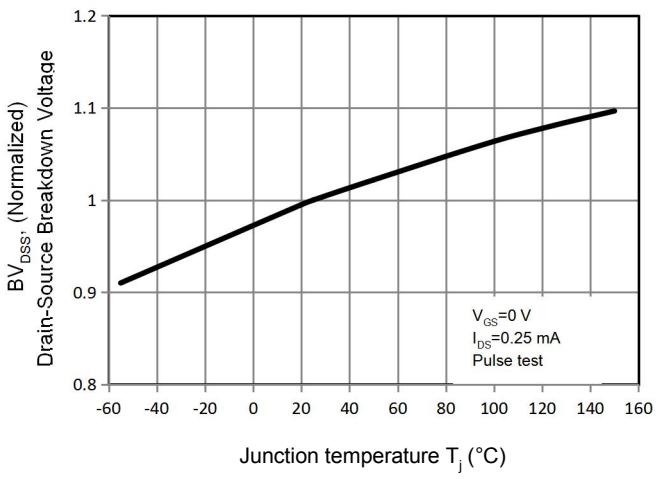


Figure 6. On-Resistance vs. Temperature

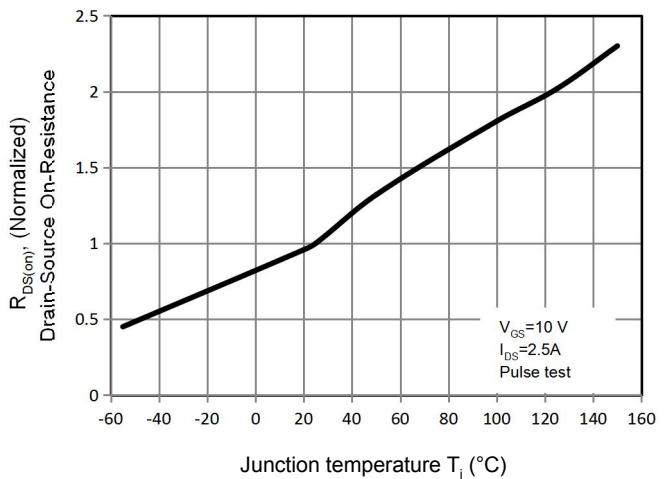


Figure 7. Capacitance Characteristics

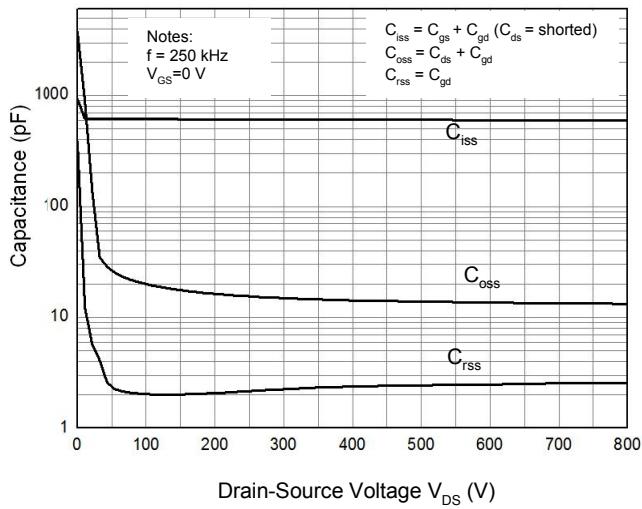


Figure 8. Gate Charge Characterist

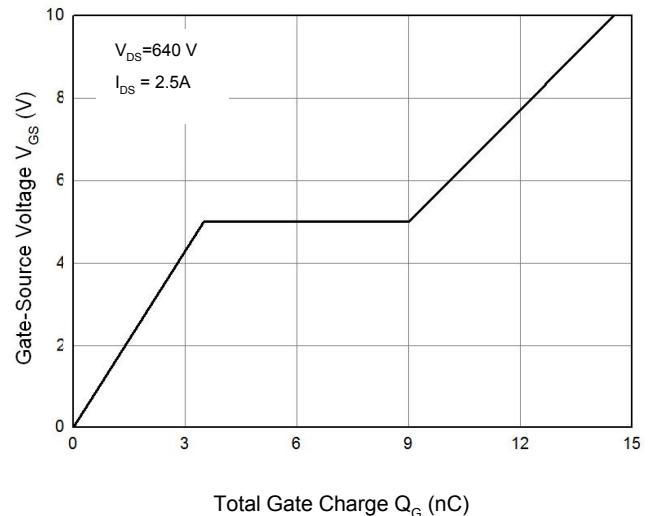


Figure 9.1 Maximum Safe Operating Area
TO-220MF

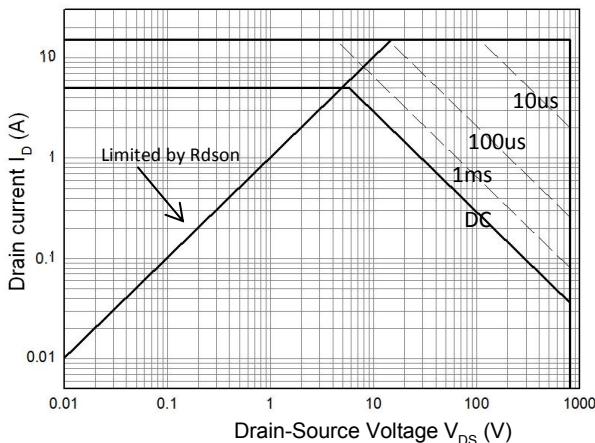


Figure 9.2 Maximum Safe Operating Area
TO-220/TO-252/TO-263

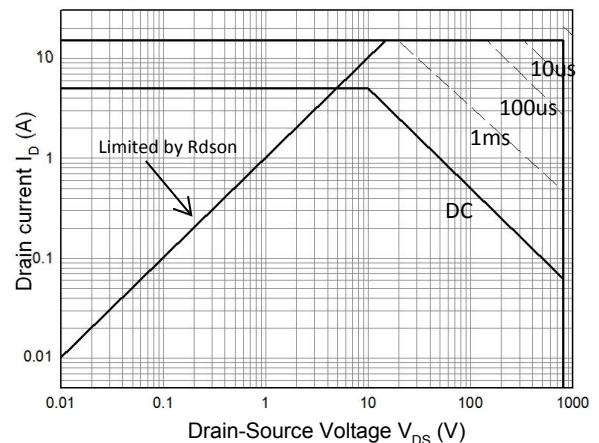


Figure 10.1 Power Dissipation vs. Temperature
TO-220MF

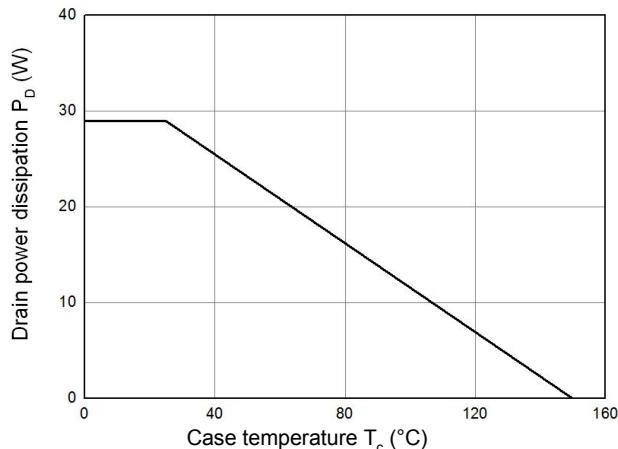
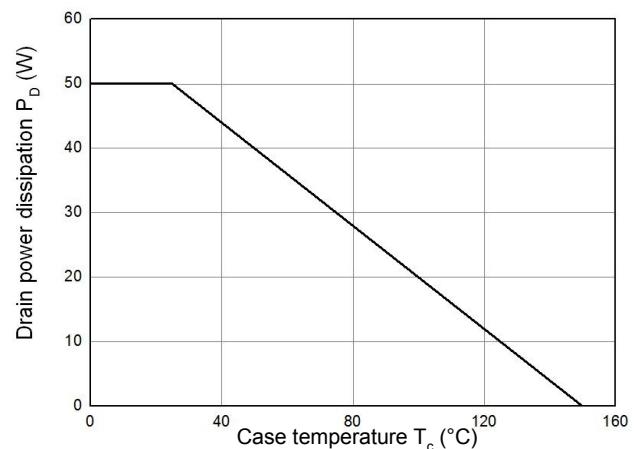
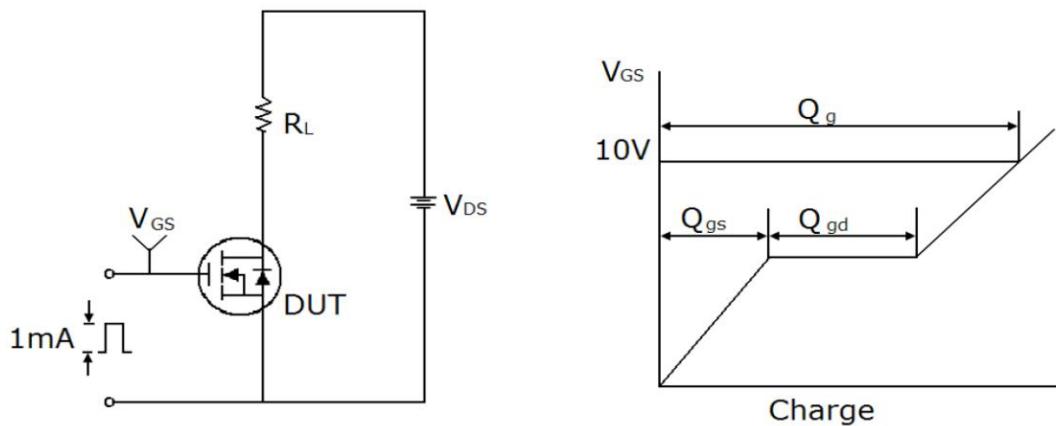


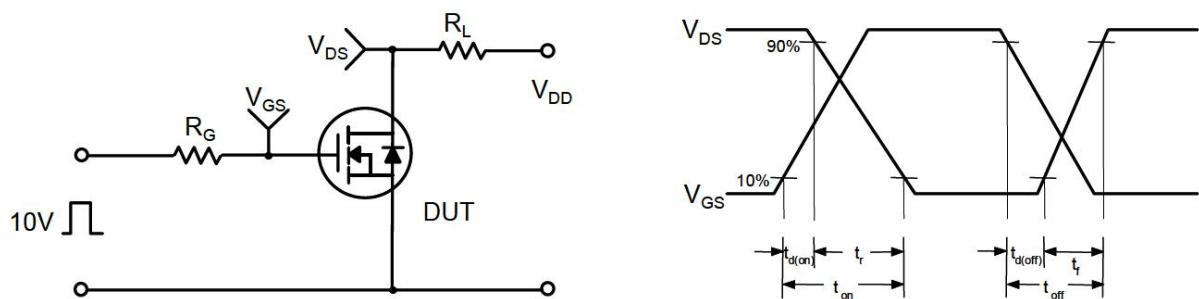
Figure 10.2 Power Dissipation vs. Temperature
TO-220/TO-252/TO-263



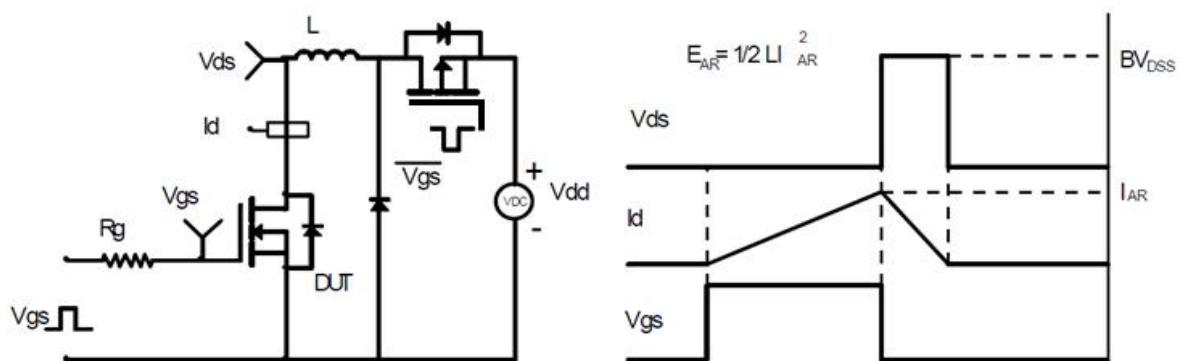
Gate Charge Test Circuit & Waveform



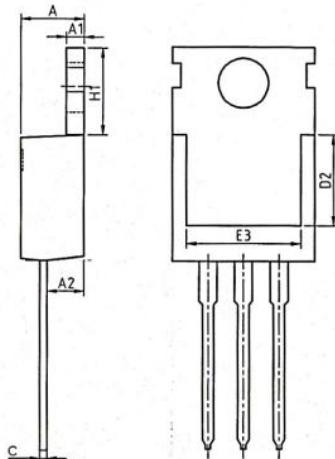
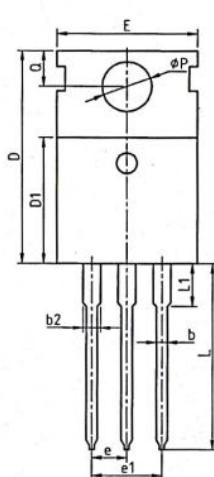
Switching Test Circuit & Waveforms



Unclamped Inductive Switching Test Circuit & Waveforms

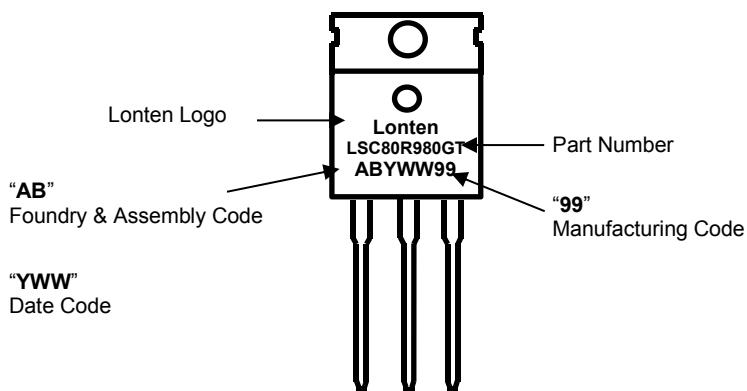


Mechanical Dimensions for TO-220

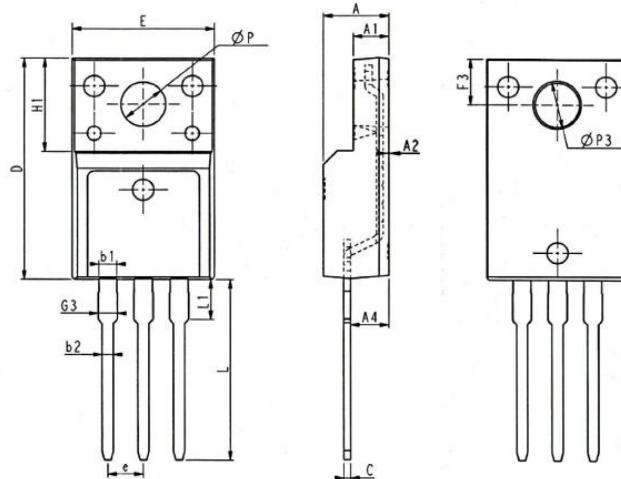


| SYMBOL | COMMON DIMENSIONS | | | | | |
|--------|-------------------|-------|-------|--------|-------|-------|
| | MM | | | INCH | | |
| | MIN | NOM | MAX | MIN | NOM | MAX |
| A | 4.37 | 4.57 | 4.70 | 0.172 | 0.180 | 0.185 |
| A1 | 1.25 | 1.30 | 1.40 | 0.049 | 0.051 | 0.055 |
| A2 | 2.20 | 2.40 | 2.60 | 0.087 | 0.094 | 0.102 |
| b | 0.70 | 0.80 | 0.95 | 0.028 | 0.031 | 0.037 |
| b2 | 1.17 | 1.27 | 1.47 | 0.046 | 0.050 | 0.058 |
| c | 0.45 | 0.50 | 0.60 | 0.018 | 0.020 | 0.024 |
| D | 15.10 | 15.60 | 16.10 | 0.594 | 0.614 | 0.634 |
| D1 | 8.80 | 9.10 | 9.40 | 0.346 | 0.358 | 0.370 |
| D2 | 5.50 | — | — | 0.217 | — | — |
| E | 9.70 | 10.00 | 10.30 | 0.382 | 0.394 | 0.406 |
| E3 | 7.00 | — | — | 0.276 | — | — |
| e | 2.54BSC | | | 0.1BSC | | |
| e1 | 5.08BSC | | | 0.2BSC | | |
| H1 | 6.25 | 6.50 | 6.85 | 0.246 | 0.256 | 0.270 |
| L | 12.75 | 13.50 | 13.80 | 0.502 | 0.531 | 0.543 |
| L1 | — | 3.10 | 3.40 | — | 0.122 | 0.134 |
| Øp | 3.40 | 3.60 | 3.80 | 0.134 | 0.142 | 0.150 |
| Q | 2.60 | 2.80 | 3.00 | 0.102 | 0.110 | 0.118 |

TO-220 Part Marking Information

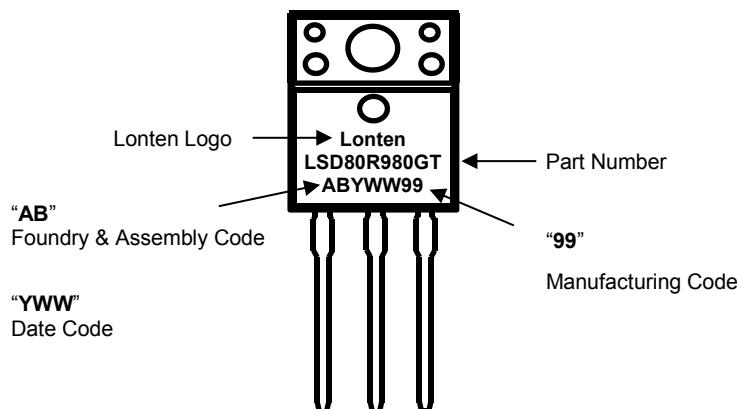


Mechanical Dimensions for TO-220MF

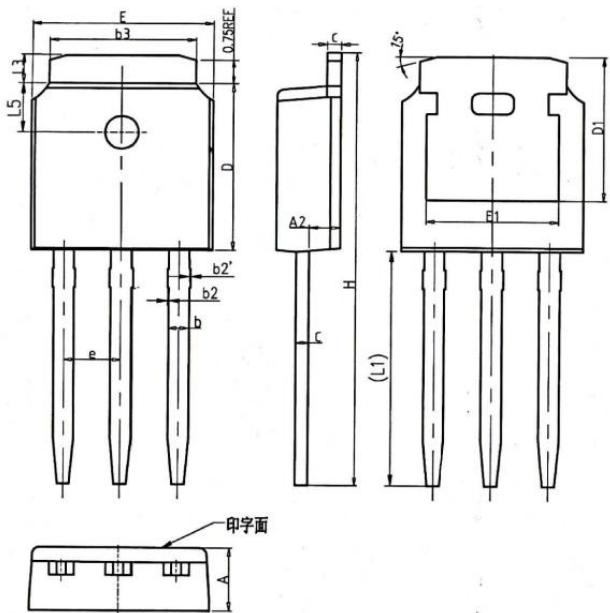


| SYMBOL | COMMON DIMENSIONS | | | INCH | | |
|--------|-------------------|------|------|----------|------|------|
| | MIN | NOM | MAX | MIN | NO | MA |
| E | 9.96 | 10.1 | 10.3 | 0.39 | 0.40 | 0.40 |
| A | 4.50 | 4.70 | 4.90 | 0.17 | 0.18 | 0.19 |
| A1 | 2.34 | 2.54 | 2.74 | 0.09 | 0.10 | 0.10 |
| A2 | 0.30 | 0.45 | 0.60 | 0.01 | 0.00 | 0.02 |
| A4 | 2.65 | 2.76 | 2.96 | 0.10 | 0.10 | 0.11 |
| C | 0.40 | 0.50 | 0.38 | 0.01 | 0.02 | 0.02 |
| D | 15.57 | 15.8 | 16.1 | 0.61 | 0.62 | 0.63 |
| H1 | 6.70REF | | | 0.264REF | | |
| e | 2.54BSC | | | 0.1BSC | | |
| ØP | 3.03 | 3.18 | 3.38 | 0.11 | 0.12 | 0.13 |
| L | 12.68 | 12.9 | 13.2 | 0.49 | 0.51 | 0.52 |
| L1 | 2.88 | 3.03 | 3.18 | 0.11 | 0.11 | 0.12 |
| ØP3 | 3.15REF | | | 0.124REF | | |
| F3 | 3.15 | 3.30 | 3.45 | 0.12 | 0.13 | 0.13 |
| G3 | 1.25 | 1.35 | 1.55 | 0.04 | 0.05 | 0.06 |
| b1 | 1.18 | 1.28 | 1.43 | 0.04 | 0.05 | 0.05 |
| b2 | 0.70 | 0.80 | 0.95 | 0.02 | 0.03 | 0.03 |

TO-220MF Part Marking Information

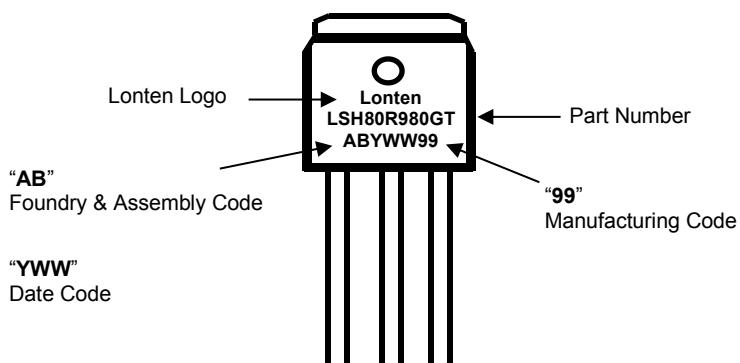


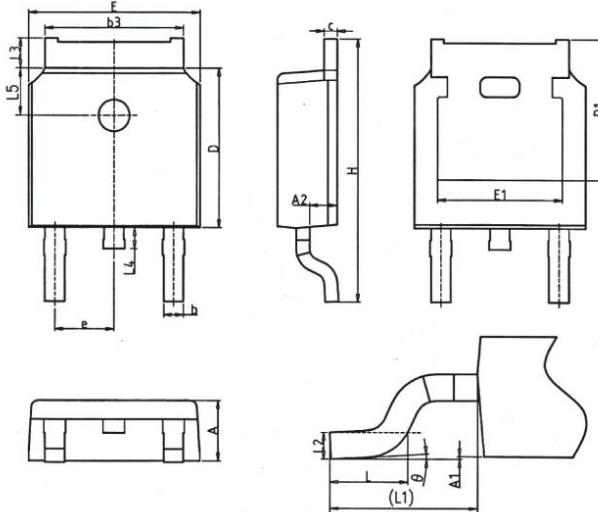
Mechanical Dimensions for TO-251



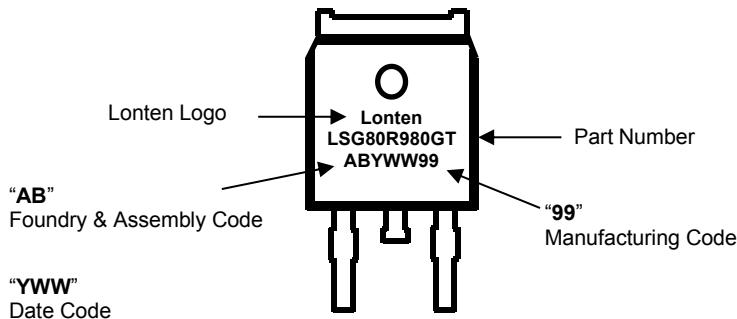
| COMMON DIMENSIONS | | | |
|-------------------|----------|-------|-------|
| SYMBOL | MM | | |
| | MIN | NOM | MAX |
| A | 2.20 | 2.30 | 2.38 |
| A2 | 0.97 | 1.07 | 1.17 |
| b | 0.68 | 0.78 | 0.90 |
| b2 | 0.00 | 0.04 | 0.10 |
| b2' | 0.00 | 0.04 | 0.10 |
| b3 | 5.20 | 5.33 | 5.46 |
| c | 0.43 | 0.53 | 0.61 |
| D | 5.98 | 6.10 | 6.22 |
| D1 | 5.30REF | | |
| E | 6.40 | 6.60 | 6.73 |
| E1 | 4.63 | — | — |
| e | 2.286BSC | | |
| H | 16.22 | 16.52 | 16.82 |
| L1 | 9.15 | 9.40 | 9.65 |
| L3 | 0.88 | 1.02 | 1.28 |
| L5 | 1.65 | 1.80 | 1.95 |

TO-251 Part Marking Information

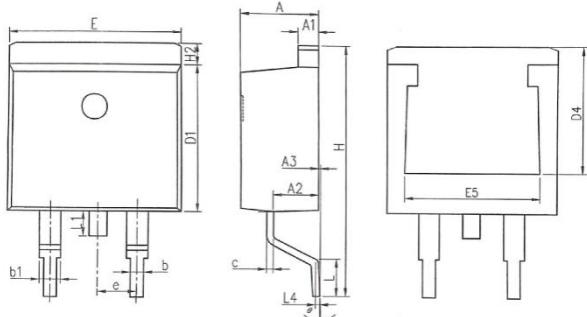


Mechanical Dimensions for TO-252


| SYMBOL | COMMON DIMENSIONS | | | |
|--------|-------------------|-------|-------|-----|
| | mm | MIN | NOM | MAX |
| A | 2.20 | 2.30 | 2.38 | |
| A1 | 0.00 | — | 0.20 | |
| A2 | 0.97 | 1.07 | 1.17 | |
| b | 0.68 | 0.78 | 0.90 | |
| b3 | 5.20 | 5.33 | 5.46 | |
| c | 0.43 | 0.53 | 0.61 | |
| D | 5.98 | 6.10 | 6.22 | |
| D1 | 5.30REF | | | |
| E | 6.40 | 6.60 | 6.73 | |
| E1 | 4.63 | — | — | |
| e | 2.286BSC | | | |
| H | 9.40 | 10.10 | 10.50 | |
| L | 1.38 | 1.50 | 1.75 | |
| L1 | 2.90REF | | | |
| L2 | 0.51BSC | | | |
| L3 | 0.88 | — | 1.28 | |
| L4 | 0.50 | — | 1.00 | |
| L5 | 1.65 | 1.80 | 1.95 | |
| θ | 0° | — | 8° | |

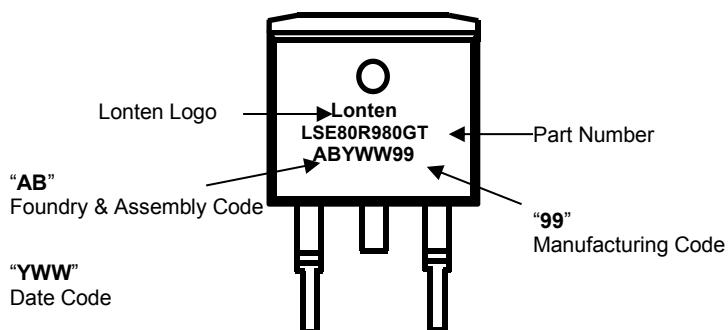
TO-252 Part Marking Information


Mechanical Dimensions for TO-263

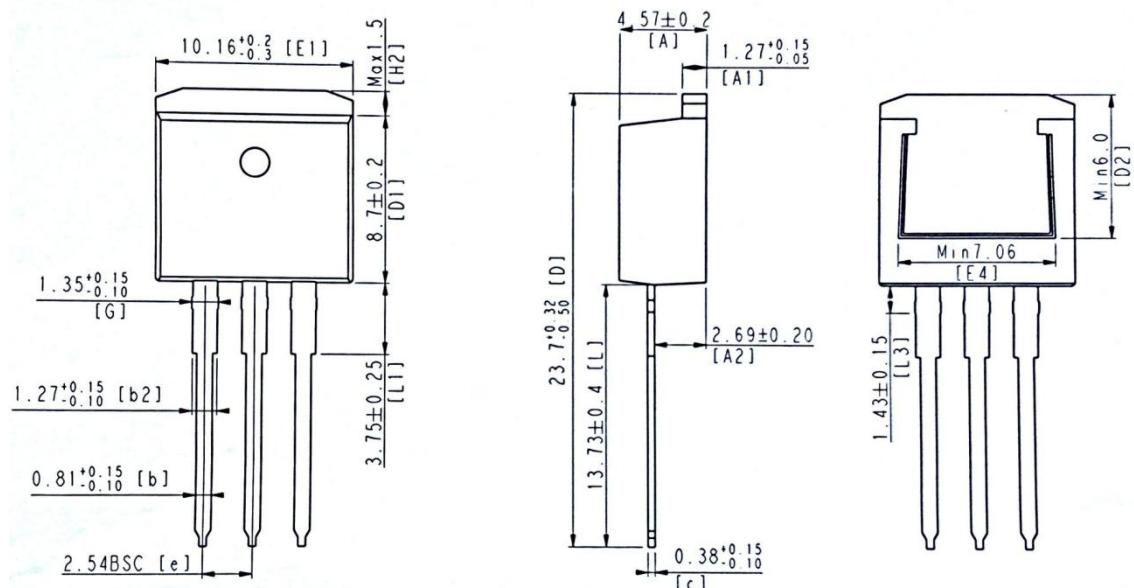


| SYMBOL | COMMON DIMENSIONS | | | | | |
|--------|-------------------|-------|-------|-----------|--------|--------|
| | MM | | | INCH | | |
| | MIN | NOM | MAX | MIN | NOM | MAX |
| A | 4.37 | 4.57 | 4.77 | 0.172 | 0.180 | 0.188 |
| A1 | 1.22 | 1.27 | 1.42 | 0.048 | 0.050 | 0.056 |
| A2 | 2.49 | 2.89 | 2.89 | 0.098 | 0.114 | 0.114 |
| A3 | 0.00 | 0.13 | 0.25 | 0.000 | 0.005 | 0.010 |
| b | 0.70 | 0.81 | 0.96 | 0.028 | 0.032 | 0.034 |
| b1 | 1.17 | 1.27 | 1.47 | 0.046 | 0.050 | 0.058 |
| c | 0.30 | 0.38 | 0.53 | 0.012 | 0.015 | 0.021 |
| D1 | 8.50 | 8.70 | 8.90 | 0.335 | 0.343 | 0.350 |
| D4 | 6.60 | — | — | 0.260 | — | — |
| E | 9.86 | 10.16 | 10.36 | 0.389 | 0.400 | 0.408 |
| E5 | 7.06 | — | — | 0.278 | — | — |
| e | 2.54 BSC | | | 0.100 BSC | | |
| H | 14.70 | 15.10 | 15.50 | 0.579 | 0.594 | 0.610 |
| H2 | 1.07 | 1.27 | 1.47 | 0.042 | 0.050 | 0.058 |
| L | 2.00 | 2.30 | 2.60 | 0.079 | 0.091 | 0.102 |
| L1 | 1.40 | 1.55 | 1.70 | 0.055 | 0.061 | 0.067 |
| L4 | 0.25 BSC | | | 0.010 BSC | | |
| θ | 0° | 5° | 9° | 0° | 0.197° | 0.354° |

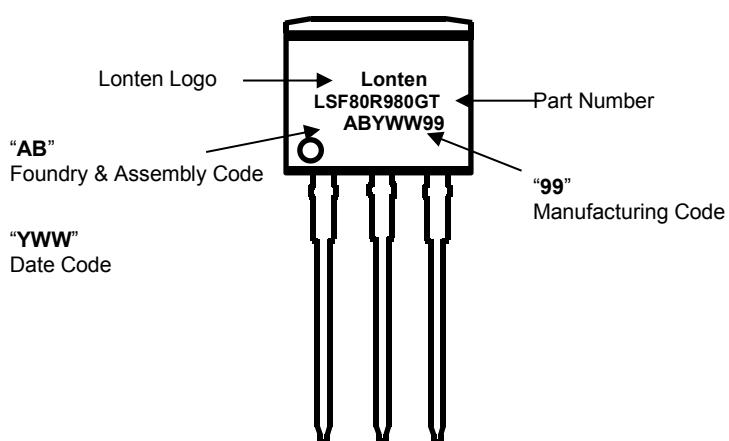
TO-263 Part Marking Information



Mechanical Dimensions for TO-262



TO-262 Part Marking Information



Disclaimer

The content specified herein is for the purpose of introducing LONTEN's products (hereinafter "Products"). The information given in this document shall in no event be regarded as a guarantee of conditions or characteristics. Examples of application circuits, circuit constants and any other information contained herein illustrate the standard usage and operations of the Products. The peripheral conditions must be taken into account when designing circuits for mass production.

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